

DESCRIPTION

BL8023C is a bi-direction relay driver circuit, used to control the magnetic latching relay, with large output capability, ultra-low power consumption. It can be widely used in smart meters and other pulses, level control applications.

BL8023C can provide 300mA typical driving current, which will different according to the relay coil resistance. The input High Level Threshold of BL8023C is 3V, making it compatible with most single chip microcontroller.

BL8023C is available in SOP-8 and DIP-8 packages.

FEATURES

- 5 to 36V input voltage range
- Low Power Consumption (Iq<1uA)
- Input High Level Threshold: 3V, compatible with most single chip microcontroller

300mA Bi-Direction Relay Driver

- Typical Driving Current: 300mA Rds(on)=12ohm (Vin=12V, PMOSFET+NMOSFET) Rds(on)=10ohm (Vin=30V, PMOSFET+NMOSFET)
- Peak Driving Current: 500mA@Vin=24V
- Environment Temperature: -40°C~85°C
- SOP-8 and DIP-8 packages

APPLICATIONS

Smart Meter



ORDERING INFORMATION

Part No.	Package	Tape & Reel
BL8023C	SOP-8	2500/Reel

PIN OUT & MARKING



8023S: Product Code LLLLL: Lot No.

TYPICAL APPLICATION

ABSOLUTE MAXIMUM RATING

Parameter			Value	
Max Input Voltage			40V	
Max Operating Junction Temperature (T _J)			150°C	
Ambient Temperature (T _A)			-40°C to 125°C	
Package Thermal Resistance	SOP-8	θ _{JA}	128°C/W	
		θις	45°C/W	
Storage Temperature (T _s)			-40°C to 150°C	
Lead Temperature & Time			260°C, 10S	

Note: Exceed these limits to damage to the device.

Exposure to absolute maximum rating conditions may affect device reliability.

RECOMMENDED WORK CONDITIONS

Parameter	Value		
Input Voltage Range	Max. 36V		
Operating Junction Temperature (T _J)	-40°C to 85°C		

ELECTRICAL CHARACTERISTICS

(V_{IN}=5V, T_A=25°C)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{IN}	Input Voltage Range		5		36	V
lα	Quiescent Current				1	uA
		V _{IN} =12V, R _L =750hm		12	18	ohm
Rds(on) Switch Rds(on)		V _{IN} =30V, R _L =750hm		10	16	ohm
	Switch Rds(0h)	V _{IN} =12V, R _L =40ohm		12	20	ohm
		V _{IN} =30V, R _L =400hm		10	16	ohm
V _{TH}	ON Input High Voltage	V _{IN} =12V		3		V
R _{IN}	Equivalent Input Resistor			500		Kohm
V _{SD}	Fly-Wheel Diode Forward Voltage	Is=1A		1.2	2	V
T _R	Rise Time	V _{IN} =12V, R _L =750hm		40		ns
T _{D(ON)}	Turn ON Delay Time	V _{IN} =12V, R _L =750hm		60		ns
T _F	Fall Time	V _{IN} =12V, R _L =75ohm		30		ns
T _{D(OFF)}	Turn OFF Delay Time	V _{IN} =12V, R _L =750hm		70		ns

Note: 1) Input rise/fall time must less than 1ms, otherwise maybe destroy the chip.

LOGIC FUNCTION TABLE

Input A	Input B	Output OA	Output OB	RELAY RESPONSE
1	0	1	0	ON
0	1	0	1	OFF
0	0	High-impedance	High-impedance	Hold
1	1	High-impedance	High-impedance	Hold

PIN DESCRIPTION				
PIN #	NAME	DESCRIPTION		
1	OA	Output A.		
2, 6	NC	Not connected.		
3	А	Input A.		
4	GND	Ground.		
5	OB	Output B.		
7	В	Input B.		
8	VIN	Supply input voltage.		

ELECTRICAL PERFORMANCE

Tested under $T_A=25^{\circ}C$, unless otherwise specified.



Turn off delay and fall time



Forward Voltage



Vth vs. Vin



BLOCK DIAGRAM

DETAILED DESCRIPTION

Pulse Triggering

If input is driven by square pulse, connect the inputs to the pulse source directly. Relay will operate as logic table stated (Vin should be less than the power supply voltage, Rs is current-limiting resistor, it can be ignored in the voltage is below 20V, i.e., Rs=0).

The recommended pulse width=100ms. The length of the intervals should be longer than 100ms. These intervals include: intervals between forward drive pulse and next backward drive pulse, intervals between forward drive pulse, intervals between backward drive pulse and next forward drive pulse, intervals between backward drive pulse and next forward drive pulse.





Relay free-wheel

Relay from ON to OFF, the energy stored in the relay inductor released by the chip's internal body diode and the relay inductor. Until the end of the release of this energy, relay proceeding to the next operation.

PACKAGE OUTLINE

